

17-Comp-A1, Electronics

3 hours duration

NOTES:

1. If doubt exists as to the interpretation of any question, the candidate is urged to indicate, with the answer, a clear statement of any assumptions made.
2. This is an OPEN BOOK exam.
Any non-communicating calculator is permitted.
3. FIVE (5) questions constitute a complete exam paper.
The first 5 questions as they appear in the answer book will be marked.
4. Each question is of equal value.

Marking Scheme

1. 20 marks total (4 parts, 5 marks each)
2. 20 marks total (4 parts, 5 marks each)
3. 20 marks total (3 parts, a)7 marks, b)7 marks, c) 6 marks)
4. 20 marks total (4 parts, 5 marks each)
5. 20 marks total (3 parts, a) 7 marks, b) 6 marks, c) 7 marks)
6. 20 marks total (4 parts, 5 marks each)
7. 20 marks total (4 parts, 5 marks each)

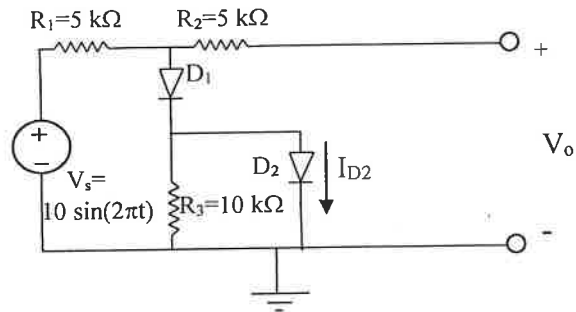
Question 1 (20 marks)

Figure 1. All diodes have a forward voltage drop $V_D=0.7V$.

The circuit shown in Figure 1 is in steady state:

- What maximum reverse voltage rating would you choose for the diodes?
- Which diode has the largest peak power dissipation? What power rating would you choose for this diode?
- Sketch V_s and V_o as a function of time, indicating peak voltages.
- Sketch current I_{D2} as a function of time, indicating peak values.

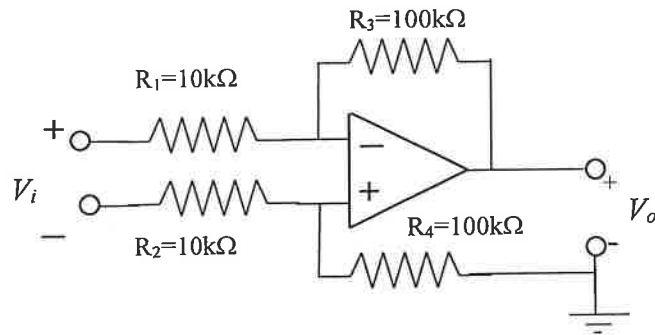
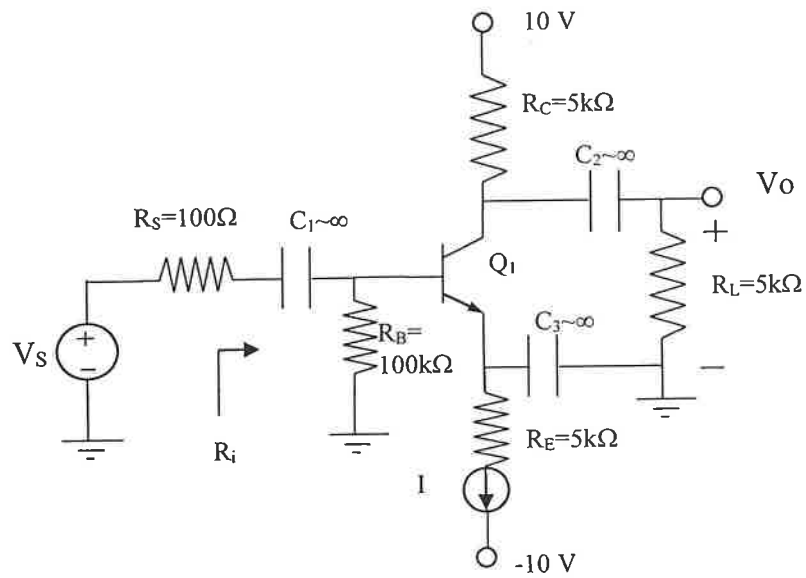
Question 3 (20 marks)

Figure 3. $+V_s=15V$, $-V_s=-15V$, $I_s=100mA$ from each supply, $V_{in}=1V@1kHz$.

For the circuit shown in Figure 3:

- Find voltage gain $|A_v|$ in dB
- Draw an equivalent circuit for the amplifier including component values
- What is the maximum input possible without clipping of the output waveform?

Question 4(20 marks)Figure 4. $I=1\text{mA}$, $\beta=100$, $V_A=100\text{V}$, $V_T=25\text{mV}$.

For the circuit shown in Figure 4:

- Find V_C , V_B and V_E .
- Draw a small signal equivalent circuit and find the model parameter values.
- Find the small signal input resistance R_i and output resistance R_o .
- Find the open circuit voltage gain for the amplifier and the loaded voltage gain.

Question 5 (20 marks)

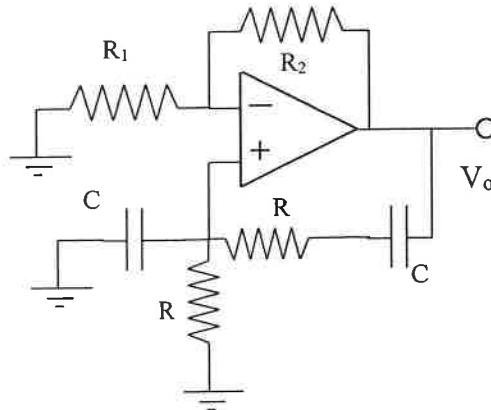


Figure 5. $R=10\text{k}\Omega$, $C=0.1\mu\text{F}$

For the circuit shown in Figure 5:

- What is the condition for oscillation of the output?
- What are the frequency and amplitude of the output signal?
- Choose component values R_1 and R_2 to sustain oscillation.

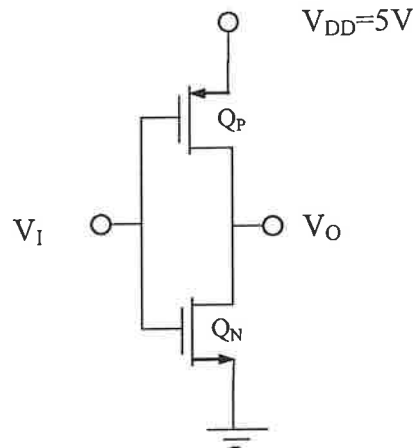
Question 6 (20 marks)

Figure 6 $k_n' = 50 \mu\text{A}/\text{V}^2$, $k_p' = 20 \mu\text{A}/\text{V}^2$, $V_{tn} = -V_{tp} = 1\text{V}$, $C_{ox} = 1\text{fF}/\mu\text{m}^2$, $V_{DD} = 5\text{V}$.

- a) If the minimum gate length for this technology is $1 \mu\text{m}$, size Q_N and Q_P to obtain a symmetric transfer characteristic.
- b) Sketch the voltage transfer characteristic, indicate the region of operation of each transistor in each region of the characteristic.
- b) Estimate the maximum capacitance this circuit can drive with a propagation delay of less than 200 ps.
- d) Based on this inverter technology synthesize a circuit to execute $Y = \overline{AB}$.

Question 7 (20 marks)

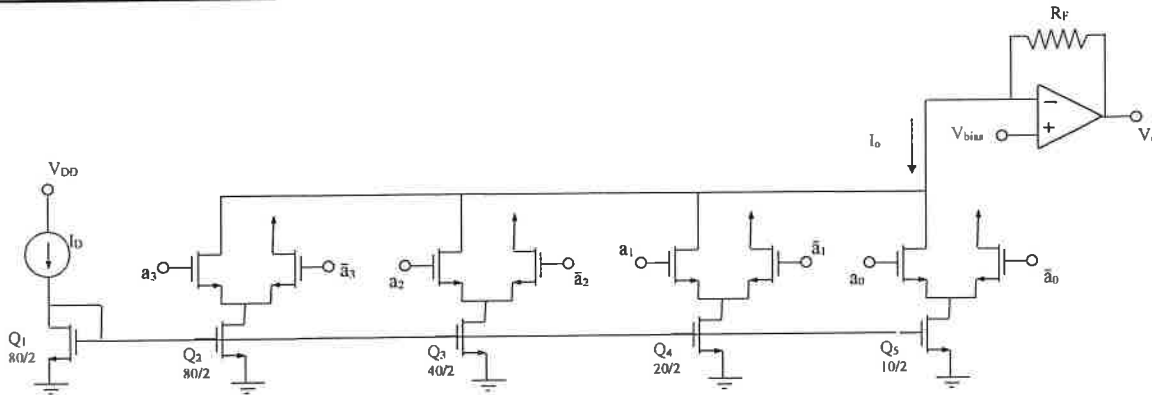


Figure 7. $I_D=0.8\text{mA}$, $R_F=1\text{k}\Omega$, $V_{DD}=5\text{V}$, $V_{\text{bias}}=2\text{V}$
 $V_t=1\text{V}$, $k'=40\ \mu\text{A}/\text{V}^2$. Transistor W/L ratios are shown.

- What is a common name for the circuit shown in Figure 7? Briefly explain how it works.
- Calculate V_{GS} for Q_1 . Calculate the drain currents for Q_2 - Q_5 .
- If a_3 - a_0 are connected to V_{DD} , find I_0 . For each value of $A_{in}=0000$ to $A_{in}=1111$ determine the output V_0 .
- What are the limitations of the application of this circuit?